The HD74LS373, 8-bit register features totem-pole three-state outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. The high-impedance third state and increased high-logic-level drive provide this register with the capacity of being connected directly to and driving the bus lines in a bus-organized system without need for interface or pull-up components. They are particularly attractive for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The eight latches are transparent D-type latches meaning that while the enable (G) is high the Q outputs will follow the data (D) inputs. When the enable is taken low the output will be latched at the level of the data that was setup.

# FUNCTION TABLE

	Output				
Output control	Enable G	D	Q		
L	н	Н	н		
L	Н	L.	L		
L	L	×	Q <sub>o</sub>		
Н	×	×	Z		

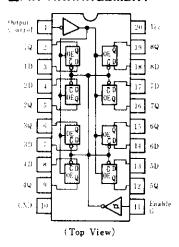
Notes: H = high level, L = low level,

X = irrelevant

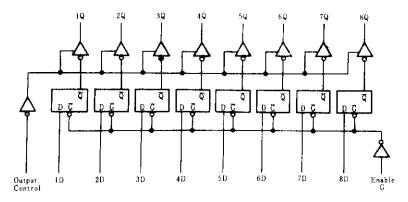
Q<sub>0</sub> = level of Q before the indicated steady-state input conditions were established.

Z = off (high-impedance) state of a three-state output

#### **PIN ARRANGEMENT**



#### ■BLOCK DIAGRAM



### **MRECOMMENDED OPERATING CONDITIONS**

Item		Symbol	min	typ	max	Unit
Supply voltage		$V_{cc}$	4.75	5.00	5.25	V
Output voltage		$V_{OH}$			5.5	V
Output current		1 он	_	_	-2.6	mА
		Ior			24	mA
Enable pulse "H" level			15			
width	"L" level	l w	15	_		ns
Data setup time		t su	5↓	-		ns
Data hold time		t s	25 ↓		_	ns

Note) 4: The arrow indicates the falling edge of clock pulse.

# **ELECTRICAL CHARACTERISTICS** $(Ta=-20\sim+75^{\circ}C)$

Item	Symbol	Test Conditions		min	typ*	max	Unit	
	VIH			2.0	_		V	
Input voltage		Data inputs				0.7	V	
	V <sub>IL</sub>	G, Output control inputs		_	0.8	<b>v</b>		
	Von	$V_{CC} = 4.75 \text{V}, \ V_{IH} = 2 \text{V}, \ V_{IL} = V_{I}$	L mex, I <sub>OH</sub> = -2.6mA	2.4			V	
Output voltage		$V_{cc}-4.75V$ , $V_{IB}-2V$ ,	Io1-12mA	_		0.4	V	
	Vol	VIL - VIL max	IoL = 24mA			0.5	V	
Off-state output current Iozu	Іогн		Vo-2.7V			20	μΑ	
	Iozi	$V_{\rm cc} = 5.25 \text{V}, V_{tH} = 2 \text{V}$	Vo-0.4V	_		-20		
	In	$V_{cc} = 5.25 \text{V}, V_l = 2.7 \text{V}$				20	μA	
Input current	In.	$V_{cc}$ = 5.25V, $V_{t}$ = 0.4V			0.4	mA		
	I,	Vcc-5.25V, V1-7V	_		0.1	mA		
Short-circuit output current	Ios	Vcc-5.25V	-30		-130	mA		
Supply current	Icc	Vcc-5.25V, Vi-4.5V (Output control)		_	24	40	mA	
Input clamp voltage	Vik	$V_{cc}=4.75$ V, $I_{IN}=-18$ mA			-1.5	V		

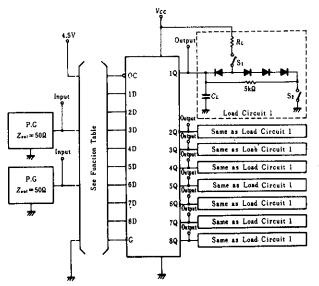
<sup>\*</sup> VCC=5V, Ta=25°C

# **ESWITCHING CHARACTERISTICS** $(V_{cc}=5\text{V}, T_a=25^{\circ}\text{C})$

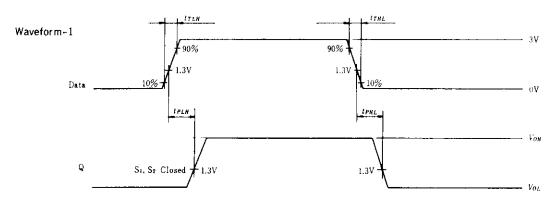
Item	Symbol	Input	Output	Test Conditions	min	typ	max	Unit
Propagation delay time	t <sub>PLH</sub>				_	12	18	
	tpHL	DQ			12	18		
	t <sub>PLH</sub>	G		$C_L = 45 \text{pF}$ $R_L = 667 \Omega$		20	30	
	t <sub>PHL</sub>		Q			18	30	
Output enable time	t <sub>ZH</sub>	ос	Q		_	15	28	n\$
	l ZL				_	25	36	
Output disable time	t <sub>HZ</sub>	OC 0		$C_L = 5pF$		12	20	
	t <sub>LZ</sub>		Q	$R_L = 667\Omega$		15	25	

# TESTING METHOD

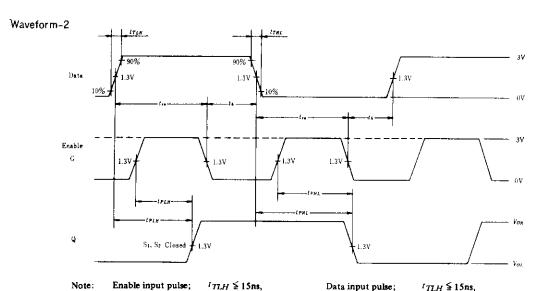
Test Circuit

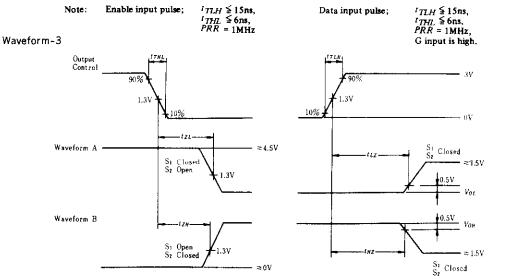


 C<sub>L</sub> includes probe jig capacitance.
 All diodes are 1\$2074 (f). Notes:



Notes: Input pulse;  $t_{TLH} \le 15$ ns,  $t_{THL} \le 6$ ns, PRR = 1MHz, duty cycle 50%

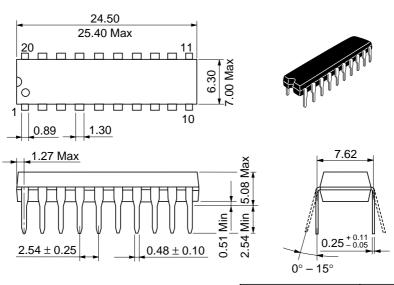




Notes:

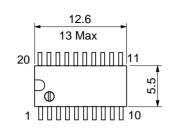
 Input pulse; t<sub>TLH</sub> ≤ 15ns, t<sub>THL</sub> ≤ 6ns, PRR = iMHz, duty cycle 50%
 Waveform A if for an output with internal conditions such that the output is low except when disabled by the output control. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.

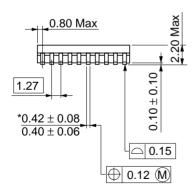
Unit: mm

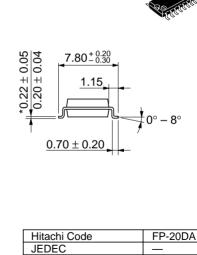


Hitachi Code	DP-20N
JEDEC	_
EIAJ	Conforms
Weight (reference value)	1.26 g

Unit: mm







Weight (reference value)

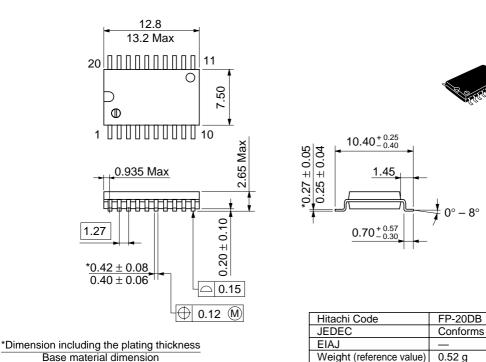
Conforms

0.31 g

EIAJ

\*Dimension including the plating thickness
Base material dimension

Unit: mm



## **Cautions**

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

# HTACHI

## Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

NorthAmerica URL Europe

http://www.hitachi-eu.com/hel/ecg http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD\_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm

http:semiconductor.hitachi.com/

http://www.hitachi.co.jp/Sicd/indx.htm Japan

#### For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road

Maidenhead Berkshire SL6 8YA, United Kingdom

Tel: <44> (1628) 585000 Fax: <44> (1628) 778322 Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666

Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218

Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

Copyright ' Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.